



# 74LVC3G34

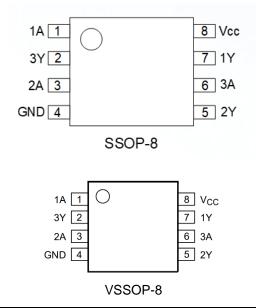
## Description

The 74LVC3G34 is a triple buffer gate with standard push-pull outputs. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output preventing damaging current backflow when the device is powered down.

Each of the buffers performs the positive Boolean function:

Y = A

## **Pin Assignments**



### Features

- Wide Supply Voltage Range from 1.65V to 5.5V
- ±24mA Output Drive at 3.3V
- CMOS Low-Power Consumption
- IOFF Supports Partial Power Down Mode Operation
- Inputs Accept up to 5.5V
- ESD Protection Tested per JESD 22
  Exceeds 2000V Human Body Model (A114)
  Exceeds 1000V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Range of Package Options
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

## Applications

- Voltage-level shifting
- General-purpose logic
- Power down signal isolation
- Wide array of products such as:
  - PCs, networking, notebooks, netbooks, PDAs
  - Computer peripherals, hard drives, CD/DVD ROM
  - TV, DVD, DVR, set top boxes
  - Cell phones, personal navigation/GPS
  - MP3 players, cameras, video recorders

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

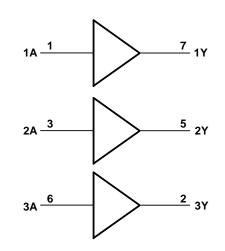
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.



## **Pin Descriptions**

Pin Name	Pin NO.	Description	
1A	1	Data Input	
3Y	2	Data Output	
2A	3	Data Input	
GND	4	Ground	
2Y	5	Data Output	
ЗA	6	Data Input	
1Y	7	Data Output	
Vcc	8	Supply Voltage	

## Logic Diagram



## **Function Table**

Inputs	Output
Α	Y
Н	Н
L	L

## Absolute Maximum Ratings (Notes 4, 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
Vcc	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High Impedance or IOFF State	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to Vcc + 0.5	V
Ік	Input Clamp Current VI < 0	-50	mA
Іок	Output Clamp Current Vo < 0	-50	mA
lo	Continuous Output Current	±50	mA
ICC, IGND	Continuous Current Through V <sub>CC</sub> or GND	±100	mA
TJ	Junction Temperature	+150	°C
Tstg	Storage Temperature	-65 to +150	°C

 Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommended values.
 Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range. Notes:



## Recommended Operating Conditions (Note 6)

Symbol	Parameter	Conditions	Min	Max	Unit	
N/		Operating	1.65	5.5	V	
Vcc	Operating Voltage	Data Retention Only	1.5	—	V	
		Vcc = 1.65V to 1.95V	0.65 X Vcc	—		
		Vcc = 2.3V to 2.7V	1.7	_	v	
Vін	High-Level Input Voltage	Vcc = 3V to 3.6V	2	—	V	
		Vcc = 4.5V to 5.5V	0.7 X Vcc	_		
		V <sub>CC</sub> = 1.65V to 1.95V	_	0.35 X V <sub>CC</sub>		
		Vcc = 2.3V to 2.7V	_	0.7	.,	
VIL	Low-Level Input Voltage	Vcc = 3V to 3.6V	_	0.8	V	
		V <sub>CC</sub> = 4.5V to 5.5V	_	0.3 X V <sub>CC</sub>	1	
VI	Input Voltage	—	0	5.5	V	
Vo	Output Voltage		0	Vcc	V	
		Vcc = 1.65V	_	-4		
		Vcc = 2.3V	_	-8		
Іон	High-Level Output Current	gh-Level Output Current	_	-16	mA	
		VC	Vcc = 3V	_	-24	
		$V_{CC} = 4.5V$	_	-32		
		Vcc = 1.65V	—	4		
		$V_{CC} = 2.3V$	—	8		
IOL	Low-Level Output Current	Vcc = 3V	_	16	mA	
		VCC = 3V	—	24		
		$V_{CC} = 4.5V$	—	32		
		$V_{CC} = 1.8V \pm 0.15V, 2.5V \pm 0.2V$	—	20		
$\Delta t / \Delta V$	Input Transition Rise or Fall Rate	Vcc = 1.65V to 2.7V	_	10 1		
		Vcc = 2.7V to 5V	_	5		
TA	Operating Free-Air Temperature	_	-40	+125	°C	

Note: 6. Unused inputs should be held at  $V_{CC}$  or Ground for device proper operation.



## **Electrical Characteristics**

Sumbol	Parameter	<b>T</b> ( <b>0</b> )		-40ºC to	+85⁰C	-40ºC to	+125⁰C	Unit
Symbol Parameter	Farameter	Test Conditions	Vcc	Min	Max	Min	Max	Unit
	I <sub>OH</sub> = -100µА	1.65V to 5.5V	V <sub>CC</sub> -0.1	—	Vcc-0.1	_		
		Iон = -4mA	1.65V	1.2	—	1.2	_	
Maria	Lligh Lough Output Valtage	Iон = -8mA	2.3V	1.9	—	1.9	_	V
Vон	High-Level Output Voltage	Iон = -16mA		2.4	—	2.4	_	V
		Iон = -24mA	3V	2.3	_	2.3	_	
		Iон = -32mA	4.5V	3.8	—	3.8	_	
		IoL = 100μA	1.65V to 5.5V	_	0.1	_	0.1	- V
		IoL = 4mA	1.65V	_	0.45	_	0.45	
		I <sub>OL</sub> = 8mA	2.3V	_	0.3	_	0.3	
Vol	Low-Level Output Voltage	IoL = 16mA	- 3V	_	0.4	_	0.4	
		IoL = 24mA		_	0.55	_	0.75	
		I <sub>OL</sub> = 32mA	4.5V	_	0.55	_	0.75	
li	Input Current	VI = 5.5V or GND	0 to 5.5V	_	±5	_	±5	μA
IOFF	Power Down Leakage Current	$V_1 \text{ or } V_0 = 5.5 V$	0	_	±10	_	±10	μA
lcc	Supply Current	$V_I = 5.5V$ or GND, $I_O = 0$	1.65V to 5.5V	_	10	_	10	μA
ΔI <sub>CC</sub>	Additional Supply Current	Input at V <sub>CC</sub> – 0.6V	3V to 5.5V	_	500	_	500	μA
Cı	Input Capacitance	$V_I = V_{CC}$ or GND	3.3V	_	3.5 (Typ)	_	_	pF

## **Package Characteristics**

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
C Thermal Desistance lunction to Ambien		SSOP-8	Note 7	_	130	_	°C/W
ΘJA	Thermal Resistance Junction-to-Ambient	VSSOP-8	Note 7	_	155	_	°C/W
0.4	Thermal Desistance, Junction to Case	SSOP-8	Note 7	_	36	_	°C/W
Өлс	Thermal Resistance Junction-to-Case	VSSOP-8	Note 7	—	38	_	°C/W

Note: 7. Test condition: Device mounted on JEDEC 2s2p High-K board, FR-4 substrate PCB, 2oz copper with minimum recommended pad layout.

## **Operating Characteristics** (T<sub>A</sub> = +25°C, V<sub>CC</sub> = 3.3V)

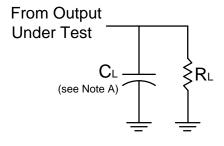
Symbol	Parameter	Test Conditions	Vcc = 1.8V Typ	Vcc = 2.5V Typ	Vcc = 3.3V Typ	Vcc = 5V Typ	Unit
Cpd	Power Dissipation Capacitance	f = 10MHz, 1 Input Switching	19	19	19	21	pF



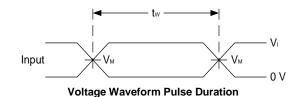
## **Switching Characteristics**

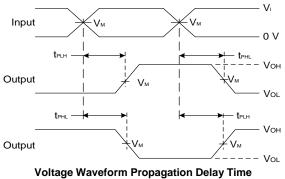
Figure 1								
Parameter	Personator From To	То		T <sub>A</sub> = -40°C to +85°C		T <sub>A</sub> = -40°C to +125°C		Unit
Farameter	Input	Output	Vcc	Min	Max	Min	Max	Unit
	A Y		1.8V ± 0.15V	3.2	7.9	3.2	8.9	
			2.5V ± 0.2V	1.5	4.4	1.5	5.4	
t <sub>PD</sub>		3.3V ± 0.3V	1.4	4.1	1.4	5.1	ns	
		5.0V ± 0.5V	1.1	3.2	1.1	3.8		

## Parameter Measurement Information (Notes B, C, D)



Vcc	In	puts	V <sub>M</sub>	C∟	RL	
VCC	Vı	tr/tf	UNI	91		
1.8V ± 0.15V	Vcc	≤2ns	Vcc / 2	30pF	1kΩ	
2.5V ± 0.2V	Vcc	≤2ns	V <sub>CC</sub> / 2	30pF	500Ω	
3.3V ± 0.3V	3V	≤2.5ns	1.5V	50pF	500Ω	
5.0V ± 0.5V	Vcc	≤2.5ns	V <sub>CC</sub> / 2	50pF	500Ω	





Voltage Waveform Propagation Delay Time Inverting and Noninverting Outputs

#### Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

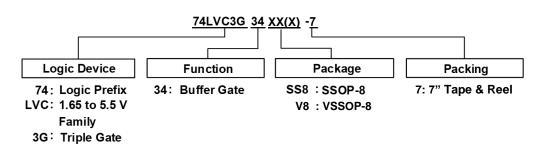
B. All pulses are supplied at pulse repetition rate  $\leq$  10MHz.

C. Inputs are measured separately one transition per measurement.

D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$ .



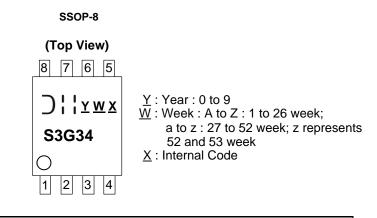
## **Ordering Information**



		-	Pac	king
Part Number	Package Code	Package	Qty.	Carrier
74LVC3G34SS8-7	SS8	SSOP-8	3000	7" Tape and Reel (Note 8)
74LVC3G34V8-7	V8	VSSOP-8	3000	7" Tape and Reel (Note 8)

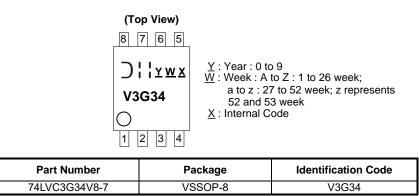
Note: 8. The taping orientation is located on our website at http://www.diodes.com/package-outlines.html.

## **Marking Information**



Part Number	Package	Identification Code
74LVC3G34SS8-7	SSOP-8	S3G34







SSOP-8

Max

1.30

0.15

1.20

0.30

0.23

3.15 4.25

2.90

0.60

0.675

8°

0.20

0.25

0.10

0.13

Max

0.90

0.10

0.80

0.25

0.13

2.10

3.60

2.40

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0.40

0.60

6°

0.20

0.25

0.10

0.13

Тур

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---

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0.21

---

2.00

3.40

2.30

0.50

0.35

0.55

3°

Тур

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1.05

0.225

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2.95

4.00

2.80

0.65

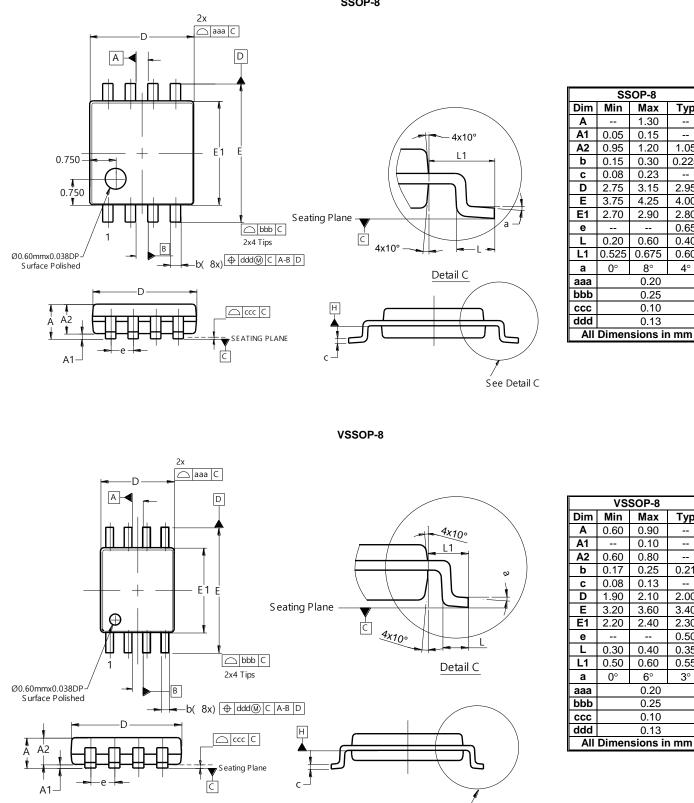
0.40

0.60

4°

## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



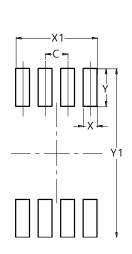
SSOP-8

Detail C



## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
Х	0.400
X1	2.350
Y	1.100
Y1	4.900

Value

(in mm)

0.500

0.250

1.750

0.750

4.050

Dimensions

С

Х

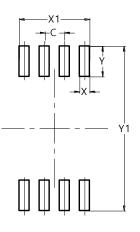
X1

Υ

Y1

VSSOP-8

SSOP-8



## **Mechanical Data**

#### SSOP-8

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Mate Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.0169 grams (Approximate)

#### VSSOP-8

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Mate Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.011 grams (Approximate)



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